



30V N-Channel Enhancement Mode MOSFET - ESD Protected

Voltage

30 V

Current

500mA

Features

- RDS(ON), VGS@4.5V, ID@500mA<1.2Ω
- RDS(ON) , VGS@2.5V, ID@200mA<1.6Ω
- RDS(ON) , VGS@1.8V, ID@100mA<2.3Ω
- RDS(ON), VGS@1.5V, ID@10mA<2.3Ω(typ.)
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. (Halogen Free)

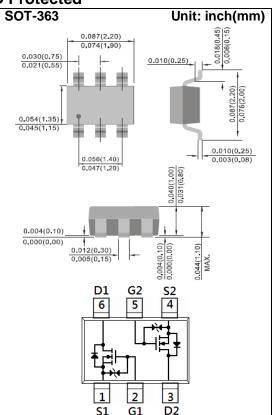
Mechanical Data

• Case: SOT-363 Package

• Terminals: Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.0002 ounces, 0.006 grams

Marking: T12



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	30	V
Gate-Source Voltage		V_{GS}	<u>+</u> 10	V
Continuous Drain Current		I _D	500	mA
Pulsed Drain Current (Note 4)		I _{DM}	1500	mA
Power Dissipation	T _a =25°C	P _D	350	mW
	Derate above 25°C		2.8	mW/°C
Operating Junction and Storage Temperature Range		T_{J}, T_{STG}	-55~150	°C
Typical Thermal resistance				
- Junction to Ambient (Note 3)		$R_{\theta JA}$	357	°C/W





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	0.6	0.85	1.1	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =500mA	-	0.87	1.2	Ω
		V _{GS} =2.5V, I _D =200mA	-	1.25	1.6	
		V _{GS} =1.8V, I _D =100mA	-	1.6	2.3	
		V _{GS} =1.5V, I _D =10mA	-	2.3	-	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =30V, V_{GS} =0V	-	0.01	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 8V, V _{DS} =0V	-	-	<u>+</u> 10	
		$V_{GS}=\pm 5V, V_{DS}=0V$	-	-	<u>+</u> 1	
Dynamic (Note 5)						
Total Gate Charge	Q_g	V _{DS} =15V, I _D =500mA, V _{GS} =4.5V ^(Note 1,2)	-	0.87	-	nC
Gate-Source Charge	Q_gs		-	0.26	-	
Gate-Drain Charge	Q_gd		-	0.16	-	
Input Capacitance	Ciss	V _{DS} =15V, V _{GS} =0V,	-	34	-	pF
Output Capacitance	Coss		-	8.9	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	2.5	-	
Turn-On Delay Time	td _(on)	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	-	7.1	-	ns
Turn-On Rise Time	tr	V_{DD} =15V, I_{D} =80mA,	-	20	-	
Turn-Off Delay Time	td _(off)	V_{GS} =4.0V, R_{G} =6 Ω (Note 1,2)	-	41	-	
Turn-Off Fall Time	tf	K _G =012	-	31	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	Is		-	-	500	mA
Diode Forward Current						
Diode Forward Voltage	V_{SD}	I _S =500mA, V _{GS} =0V	-	0.88	1.3	V

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

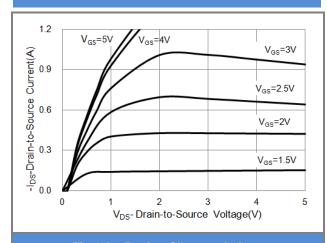


Fig.1 On-Region Characteristics

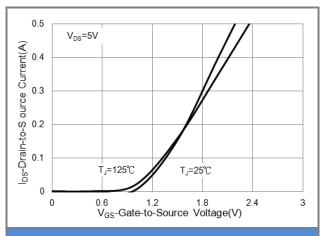


Fig.2 Transfer Characteristics

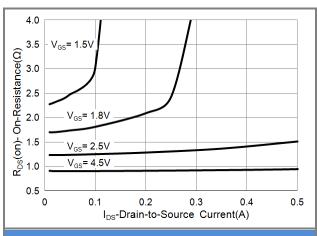


Fig.3 On-Resistance vs. Drain Current

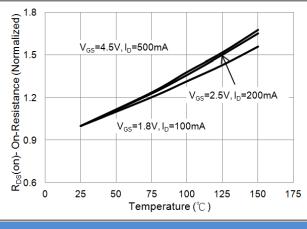
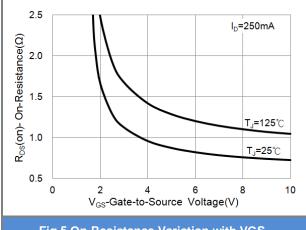
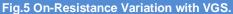
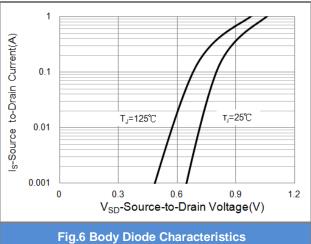


Fig.4 On-Resistance vs. Junction temperature











TYPICAL CHARACTERISTIC CURVES

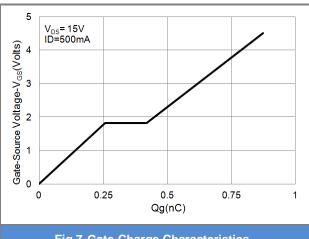


Fig.7 Gate-Charge Characteristics

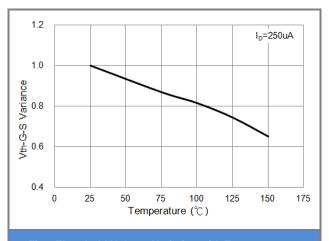


Fig.8 Threshold Voltage Variation with Temperature.

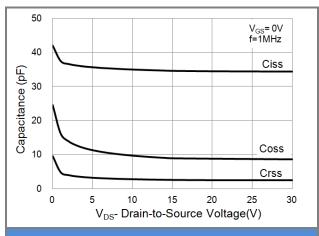


Fig.9 Capacitance vs. Drain-Source Voltage.

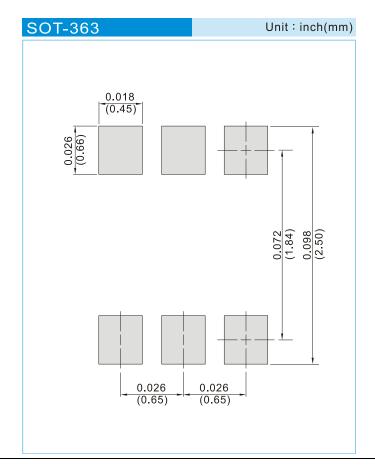




PART NO PACKING CODE VERSION

PART NO PACKING CODE	Package Type	Packing type	Marking	Version
PJT7812_R1_00001	SOT-363	3K pcs / 7" reel	T12	Halogen free
PJT7812_R2_00001	SOT-363	12K pcs / 13" reel	T12	Halogen free

MOUNTING PAD LAYOUT







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